

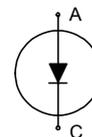
Fast switching diode chip in EMCON 3 -Technology

Features:

- 650V EMCON 3 technology 65 μm chip
- Soft, fast switching
- Low reverse recovery charge
- Small temperature coefficient
- Qualified according to JEDEC for target applications

Recommended for:

- Power module
- Discrete components



Applications:

- Drives
- White goods
- Resonant applications

Chip Type	V_R	$I_{Fn}^{1)}$	Die Size	Package
SIDC06D65C8	650V	20A	2.34 x 2.42 mm ²	sawn on foil

¹⁾ nominal forward current at $T_c = 100^\circ\text{C}$, not subject to production test - verified by design/characterisation

Mechanical Parameters

Die size		2.34 x 2.42	mm ²
Area total		5.66	
Anode pad size		1.91 x 1.99	
Thickness		65	μm
Wafer size		200	mm
Max. possible chips per wafer		4938	
Passivation frontside		Photoimide	
Pad metal		3200 nm AlSiCu	
Backside metal		Ni Ag –system	
Die bond		Electrically conductive epoxy glue and soft solder	
Wire bond		Al, $\leq 500\mu\text{m}$	
Reject ink dot size		$\varnothing 0.65\text{mm}$; max 1.2mm	
Storage environment	for original and sealed MBB bags	Ambient atmosphere air, Temperature $17^\circ\text{C} - 25^\circ\text{C}$, < 6 month	
	for open MBB bags	Acc. to IEC62258-3: Atmosphere >99% Nitrogen or inert gas, Humidity <25%RH, Temperature $17^\circ\text{C} - 25^\circ\text{C}$, < 6 month	



SIDC06D65C8

Maximum Ratings

Parameter	Symbol	Condition	Value	Unit
Repetitive peak reverse voltage	V_{RRM}	$T_{vj} = 25\text{ °C}$	650	V
Continuous forward current	I_F	$T_{vj} < 150\text{ °C}$	1)	A
Maximum repetitive forward current ²⁾	I_{FRM}	$T_{vj} < 150\text{ °C}$	40	
Operating junction temperature	T_{vj}		-40...+175	°C

1) depending on thermal properties of assembly

2) not subject to production test - verified by design/characterisation

Static Characteristics (tested on wafer), $T_{vj} = 25\text{ °C}$

Parameter	Symbol	Conditions	Value			Unit
			min.	typ.	max.	
Reverse leakage current	I_R	$V_R = 650\text{ V}$			0.24	µA
Cathode-Anode breakdown Voltage	V_{BR}	$I_R = 0.25\text{ mA}$	650			V
Forward voltage drop	V_F	$I_F = 20\text{ A}$	1.23	1.55	1.87	

Electrical Characteristics (not subject to production test - verified by design/characterization)

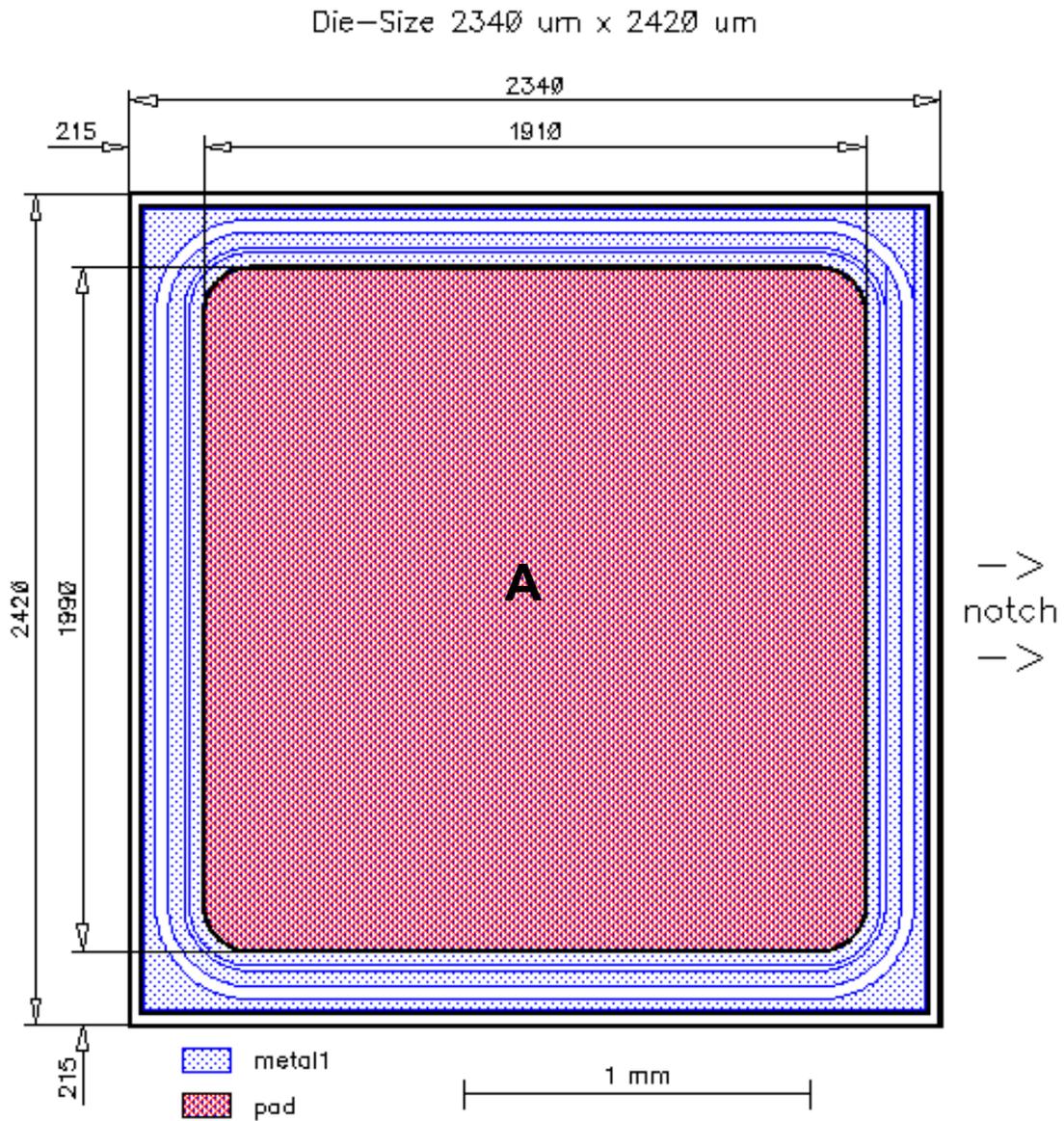
Parameter	Symbol	Conditions	Value			Unit
			min.	typ.	max.	
Forward voltage drop	V_F	$I_F = 20\text{ A}, T_{vj} = 150\text{ °C}$		1.5		V

Further Electrical Characteristics

Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

This chip data sheet refers to the device data sheet	tbd	tbd
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Chip Drawing



A: Anode pad



SIDC06D65C8

Description

AQL 0,65 for visual inspection according to failure catalogue

Electrostatic Discharge Sensitive Device according to MIL-STD 883

Revision History

Version	Subjects (major changes since last revision)	Date

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